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Substrate processing system and method of teaching transfer device

Abstract

A substrate processing system includes a load-lock module including load-lock module stages, a process module including process module stages, a vacuum transfer module that connects the load-lock module to the process module, a first transfer device that transfers substrates from the load-lock module stages to the process module stages, the first transfer device being provided in the vacuum transfer module, a second transfer device that transfers the substrates to the load-lock module stages, and a processor. The processor is configured to perform teaching a position at which the first transfer device receives the substrates from the load-lock module, teaching a position at which the first transfer device delivers the substrates to the process module, measuring shift amounts between the process module stages and the substrates mounted thereon, and correcting positions at which the second transfer device delivers the substrates to the load-lock module stages based on the measured shift amounts.

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Background/Summary

CROSS-REFERENCE TO RELATED APPLICATIONS

(1) This patent application is based on and claims priority to Japanese Patent Application No. 2021-159748 filed on Sep. 29, 2021, the entire contents of which are incorporated herein by reference.

TECHNICAL FIELD

(2) The present disclosure relates to a substrate processing system and a method of teaching a transfer device.

BACKGROUND

(3) Patent Document 1 discloses a substrate processing system including a load-lock module including multiple stages, a process chamber (a process module) including multiple stages, and a transfer device configured to transfer multiple substrates mounted on the stages of the load-lock module to the stages of the process module.

(4) The position of the stage in the process module has individual error with respect to a design value. Additionally, the error differs for each process module.

(5) One aspect of the present disclosure provides a substrate processing system that transfers a substrate in consideration of a shift of a stage and a method of teaching a transfer device.

RELATED ART DOCUMENT

(6) [Patent Document]

(7) [Patent Document 1] Japanese Laid-open Patent Application Publication No. 2020-61472

SUMMARY

(8) A substrate processing system includes a load-lock module including a plurality of load-lock module stages, a process module including a plurality of process module stages, a vacuum transfer module that connects the load-lock module to the process module, a first transfer device configured to transfer a plurality of substrates from the plurality of load-lock module stages to the plurality of process module stages, the first transfer device being provided in the vacuum transfer module, a second transfer device configured to transfer the plurality of substrates to the plurality of load-lock module stages, and a processor. The processor is configured to perform teaching a position at which the first transfer device receives the plurality of substrates from the load-lock module, teaching a position at which the first transfer device delivers the plurality of substrates to the process module, measuring shift amounts between the plurality of process module stages and the plurality of substrates mounted thereon, and correcting positions at which the second transfer device delivers the plurality of substrates to the plurality of load-lock module stages based on the measured shift amounts.

Description

BRIEF DESCRIPTION OF THE DRAWINGS

(1) FIG. 1 is a plan view illustrating an example configuration of a substrate processing system according to an embodiment;

(2) FIG. 2 is a plan view illustrating an example configuration of the substrate processing system according to the embodiment;

(3) FIG. 3A to FIG. 3D are perspective views depicting an example of an operation of mounting a wafer on a stage of a process module;

(4) FIG. 4A to FIG. 4D are perspective views depicting an example of the operation of mounting the wafer on the stage of the process module;

(5) FIG. 5 is an example of a flowchart depicting a method of teaching a transfer device in a substrate processing system according to a first embodiment;

(6) FIG. 6 is an example of a flowchart depicting a method of teaching a transfer device in a substrate processing system according to a second embodiment;

(7) FIG. 7 is an example of a plan view depicting the shift amount in each stage of the process module; and

(8) FIG. 8 is an example of a plan view depicting the correction amount in each stage of a load-lock module.

DETAILED DESCRIPTION OF EMBODIMENTS

(9) In the following, embodiments of the present disclosure will be described with reference to the drawings. In each drawing, the same components are indicated by the same reference numerals and overlapping descriptions may be omitted.

(10) <Substrate Processing System>

(11) An example of an overall configuration of a substrate processing system according to the embodiment will be described with reference to FIG. 1 and FIG. 2. FIG. 1 and FIG. 2 are plan views each illustrating an example configuration of the substrate processing system according to the embodiment. FIG. 1 illustrates an example of a state in which a wafer W is transferred into a process module PM1. FIG. 2 illustrates an example of a state before the wafer W is transferred

from a load-lock module LLM. The wafer W is illustrated with dot hatching.

(12) The substrate processing system illustrated in FIG. 1 is a cluster structure (multi-module type) system. The substrate processing system includes process modules PM1 to PM6, a transfer module VTM (a vacuum transfer module), a load-lock module LLM, loader modules LM1 to LM2, load ports LP1 to LP4, and a controller 100.

(13) The process modules PM1 to PM6 are depressurized to a predetermined vacuum atmosphere, and a desired process (an etching process, a deposition process, a cleaning process, an asking process, and the like) is performed on the semiconductor wafer W (hereinafter referred to as the “wafer W”) inside the process modules. The process modules PM1 to PM6 are disposed adjacent to the transfer module VTM. The process modules PM1 to PM6 and the transfer module VTM communicate by opening and closing gate valves GV1 to GV6. The process module PM1 includes stages 11 to 14 where a total of four wafers W are mounted in a 2×2 matrix shape in plan view. Similarly, the process modules PM2 to PM6 each include stages where four wafers W are mounted. Here, the operation of each section for processing in the process modules PM1 to PM6 is controlled by the controller 100.

(14) The transfer module VTM is depressurized to a predetermined vacuum atmosphere. Additionally, a transfer device ARM1 that transfers the wafer W is provided inside the transfer module VTM. The transfer device ARM1 carries in and carries out the wafer W between the process modules PM1 to PM6 and the transfer module VTM in accordance with the opening and closing of the gate valves GV1 to 6. The transfer device ARM1 carries in and carries out the wafers W between the load-lock module LLM and the transfer module VTM in accordance with the opening and closing of the gate valve GV7. The operation of the transfer device ARM1 and the opening and closing of the gate valves GV1 to GV7 are controlled by the controller 100.

(15) The transfer device ARM1 is configured as a multi-joint arm including a base 21, a first link 22, a second link 23, and an end effector 24. One end of the first link 22 is rotatably attached to the base 21 such that the rotational axis is the up and down direction. Additionally, the base 21 is configured to move the first link 22 in the up and down direction. One end of the second link 23 is rotatably attached to the other end of the first link 22 such that the rotational axis is the up and down direction. The base end of the end effector 24 is rotatably attached to the other end of the second link 23 such that the rotational axis is the up and down direction. At the distal end of the end effector 24, multiple holders for holding the wafers W are provided. An actuator that drives the lift of the first link 22, the joint between the base 21 and the first link 22, the joint between the first link 22 and the second link 23, and the joint between the second link 23 and the end effector 24 is controlled by the controller 100.

(16) The end effector 24 is formed in a fork shape having branches on a distal side and has a base end 240 and two blades 241 and 242 (branches of the fork shape) extending from the base end 240. The blades 241 and 242 extend in the same direction from the base end 240 and are formed at the same height. The blade 241 has holders 243 and 244 that hold multiple wafers W along the longitudinal direction of the blade 241. The blade 242 has holders 245 and 246 that hold multiple wafers W along the longitudinal direction of the blade 242. As described, the four wafers W held by the end effector 24 are held at the same height (on the same plane).

(17) Additionally, sensors S0 to S7 that detect the wafers W are provided inside the transfer module VTM. The sensor S0 detects whether the wafer W is held by the holders 243 to 246 in a state in which the end effector 24 of the transfer device ARM1 is positioned at a reference position (see FIG. 2). The sensor S1 detects whether the wafer W is held and detects the eccentricity amount of the held wafer W when the transfer device ARM1 transfers the wafer W into the process module PM1 or when the transfer device ARM1 transfers the wafer W from the process module PM1. Here, the detection method of the sensor S1 will be described later with reference to FIGS. 3A to 3D. Similarly, the sensors S2 to S6 each detect whether the wafer W is held and the eccentricity amount of the held wafer W when the transfer device ARM1 transfers the wafer W into the process

modules **PM2** to **PM6** or the transfer device **ARM1** transfers the wafer from the process modules **PM2** to **PM6**. The sensor **S7** detects whether the wafer **W** is held and detects the eccentricity amount of the held wafer **W** when the transfer device **ARM1** transfers the wafer **W** into the load-lock module **LLM** or when the transfer device **ARM1** transfers the wafer **W** from the load-lock module **LLM**. An optical passing sensor can be used for the sensors **S0** to **S7**, for example. The values detected by the sensors **S0** to **S7** are input to the controller **100**.

(18) The load-lock module **LLM** is provided between the transfer module **VTM** and the loader modules **LM1** and **LM2**. The load-lock module **LLM** is configured to switch between an ambient air atmosphere and a vacuum atmosphere. The load-lock module **LLM** and the transfer module **VTM** in the vacuum atmosphere communicate with each other by opening and closing the gate valve **GV7**. The load-lock module **LLM** and the loader module **LM1** in the ambient air atmosphere communicate with each other by opening and closing a door valve **GV8**. The load-lock module **LLM** and the loader module **LM2** in the ambient air atmosphere communicate with each other by opening and closing a door valve **GV9**. The load-lock module **LLM** includes stages **31** to **34** where a total of four wafers **W** are mounted in a 2×2 matrix shape in plan view. Additionally, the arrangement of the stages **11** to **14** of the process modules **PM1** to **PM6** and the arrangement of the stages **31** to **34** of the load-lock module **LLM** are the same. Here, the switching between the vacuum atmosphere and the ambient air atmosphere in the load-lock module **LLM** is controlled by the controller **100**.

(19) The loader modules **LM1** and **LM2** have the ambient air atmosphere in which, for example, a clean air downflow is formed. Additionally, a transfer device **ARM2** that transfers the wafer **W** is provided inside the loader module **LM1**. The transfer device **ARM2** carries in and carries out the wafer **W** between the load-lock module **LLM** and the loader module **LM1** in accordance with the opening and closing of the door valve **GV8**. Similarly, a transfer device **ARM3** that transfers the wafer **W** is provided inside the loader module **LM2**. The transfer device **ARM3** carries in and carries out the wafer **W** between the load-lock module **LLM** and the loader module **LM2** in accordance with the opening and closing of the door valve **GV9**. Additionally, a delivery section (not illustrated) where the wafer **W** is mounted is provided on the lower side of the load-lock module **LLM**. The transfer devices **ARM2** and **ARM3** can deliver the wafer **W** through the delivery section. Here, the operations of the transfer devices **ARM2** and **ARM3** and the opening and closing of the door valves **GV8** and **GV9** are controlled by the controller **100**.

(20) The transfer device **ARM2** is configured as a multi-joint arm including a base **41**, a first link **42**, a second link **43**, and an end effector **44**. One end of the first link **42** is rotatably attached to the base **41** such that the rotational axis is the up and down direction. Additionally, the base **41** is configured to move the first link **42** in the up and down direction. One end of the second link **43** is rotatably attached to the other end of the first link **42** such that the rotational axis is the up and down direction. The base end of the end effector **44** is rotatably attached to the other end of the second link **43** such that the rotational axis is the up and down direction. At the distal end of the end effector **44**, a holder **441** that holds the wafer **W** is provided. An actuator that drives the lift of the first link **42**, the joint between the base **41** and the first link **42**, the joint between the first link **42** and the second link **43**, and the joint between the second link **43** and the end effector **44** is controlled by the controller **100**. The transfer device **ARM3** is configured as a multi-joint arm substantially the same as the transfer device **ARM2**.

(21) Load ports **LP1** and **LP2** are provided on the wall of the loader module **LM1**. Additionally, load ports **LP3** and **LP4** are provided on the wall of the loader module **LM2**. A carrier **C** in which the wafer **W** is accommodated or an empty carrier **C** is attached to the load ports **LP1** to **LP4**. For example, a front opening unified pod (FOUP) or the like may be used as the carrier **C**.

(22) The transfer device **ARM2** can hold the wafer **W** accommodated in the load port **LP1** or **LP2** with the holder **441** of the transfer device **ARM2** and take out the wafer **W**. Additionally, the transfer device **ARM2** can accommodate the wafer **W** held in the holder **441** in the load port **LP1** or

LP2. Similarly, the transfer device ARM3 can hold the wafer W accommodated in the load port LP3 or LP4 with the holder of the transfer device ARM3 and take out the wafer W. Additionally, the transfer device ARM3 can accommodate the wafer W held in the holder in the load port LP3 or LP4.

(23) The controller **100** includes a central processing unit (CPU), a read only memory (ROM), a random access memory (RAM), and a hard disk drive (HDD). A storage area of the controller **100** is not limited to the HDD and the controller **100** may include another storage area such as a solid state drive (SSD). A recipe in which process procedures, process conditions, and transfer conditions are set is stored in the storage area, such as the HDD, the RAM, and the like.

(24) The CPU controls the processing of the wafer W in each process module PM according to the recipe and controls the transfer of the wafer W. The HDD or RAM may store programs for performing the processing of the wafer W and the transfer of the wafer W in each process module PM. The program may be provided in a storage medium or may be provided by an external device through a network.

(25) <Operation of the Substrate Processing System>

(26) Next, an example of an operation of the substrate processing system will be described. Here, as the example of the operation of the substrate processing system, an operation, in which the wafer W accommodated in the carrier C attached to the load port LP1 is processed in the process module PM1 and the wafer W is accommodated in the empty carrier C attached to the load port LP3, will be described. Here, at the start of the operation, the gate valves GV1 to GV7 and the door valves GV8 and GV9 are closed and the inside of the load-lock module LLM is the ambient air atmosphere.

(27) The controller **100** controls the transfer device ARM2 to take out a first wafer W from the carrier C of the load port LP1 and place the first wafer W on the delivery section (not illustrated). Additionally, the controller **100** controls the transfer device ARM2 to take out a second wafer W from the carrier C of the load port LP1 and place the second wafer W on the delivery section (not illustrated).

(28) The controller **100** opens the door valves GV8 and GV9. The controller **100** controls the transfer device ARM3 to take out the first wafer W placed in the delivery section (not illustrated) and mount the first wafer W on the stage **31** of the load-lock module LLM. In addition, the controller **100** controls the transfer device ARM2 to take out a third wafer W from the carrier C of the load port LP1 and mount the third wafer W on the stage **33** of the load-lock module LLM.

(29) Further, the controller **100** controls the transfer device ARM3 to take out the second wafer W placed in the delivery section (not illustrated) and mount the second wafer W on the stage **32** of the load-lock module LLM. In addition, the controller **100** controls the transfer device ARM2 to take out a fourth wafer W from the carrier C of the load port LP1 and mount the fourth wafer W on the stage **34** of the load-lock module LLM. Here, when the controller mounts the wafers W on the stages **31** to **34**, the controller **100** controls the transfer devices ARM2 and ARM3 based on corrected teaching positions (i.e., corrected instructed positions) (S104 and S206), which will be described later, to mount the wafers W on the stages **31** to **34**. Four wafers W are mounted on the stages **31** to **34** of the load-lock module LLM, and when the transfer devices ARM2 and ARM3 retreat from the load-lock module LLM, the controller **100** closes the door valves GV8 and GV9.

(30) The controller **100** controls an exhaust device (not illustrated) of the load-lock module LLM to exhaust air in the module and switch from the ambient air atmosphere to the vacuum atmosphere in the load-lock module LLM.

(31) The controller **100** controls the transfer device ARM1 to move the end effector **24** to the reference position. The controller **100** checks that the wafer W is not held in the blade **241** or **242** with the sensor S0. The controller **100** opens the gate valve GV7. The controller **100** controls the transfer device ARM1 to insert the blades **241** and **242** of the end effector **24** into the load-lock module LLM to reach the teaching position in the load-lock module LLM that is set in advance.

The controller **100** controls the transfer device **ARM1** to hold the wafers **W** mounted on the stages **31** to **34** of the load-lock module **LLM** and transfer the wafers **W** to the transfer module **VTM**. Here, when receiving the wafers **W** from the stages **31** to **34**, the controller **100** controls the transfer device **ARM1** based on the teaching position (**S101** and **S201**), which will be described later, and receives the wafers **W** from the stages **31** to **34**. The arrangement of the stages **31** to **34** of the load-lock module **LLM** is the same as the arrangement of the stages **11** to **14** of the process module **PM1**. Therefore, the arrangement of the wafers **W** held in the blades **241** and **242** of the end effector **24** is substantially the same as the arrangement of the stages **11** to **14** of the process module **PM1**. When the end effector **24** retreats from the load-lock module **LLM**, the controller **100** closes the gate valve **GV7**.

(32) The controller **100** opens the gate valve **GV1**. The controller **100** controls the transfer device **ARM1** to insert the blades **241** and **242** of the end effector **24** into the process module **PM1** to the teaching position in the process module **PM1** that is set in advance and mount the held wafers **W** on the stages **11** to **14** of the process module **PM1**. Here, when mounting the wafers **W** on the stages **11** to **14**, the controller **100** controls the transfer device **ARM1** based on the teaching position (**S102** and **S205**), which will be described later, to mount the wafers **W** on the stages **11** to **14**. When the end effector **24** retreats from the process module **PM1**, the controller **100** closes the gate valve **GV1**.

(33) The controller **100** controls the process module **PM1** to perform a desired process on the wafers **W**.

(34) When the processing of the wafers **W** is completed, the controller **100** opens the gate valve **GV1**. The controller **100** controls the transfer device **ARM1** to insert the blades **241** and **242** of the end effector **24** into the process module **PM1** to the teaching position in the process module **PM1** that is set in advance. The controller **100** controls the transfer device **ARM1** to hold the wafers **W** mounted on the stages **11** to **14** of the process module **PM1** and transfer the wafers **W** to the transfer module **VTM**. When the end effector **24** retreats from the process module **PM1**, the controller **100** closes the gate valve **GV1**.

(35) The controller **100** opens the gate valve **GV7**. The controller **100** controls the transfer device **ARM1** to insert the blades **241** and **242** of the end effector **24** into the load-lock module **LLM** to the teaching position of the load-lock module **LLM** that is set in advance, and mount the held wafers **W** on the stages **31** to **34** of the load-lock module **LLM**. When the end effector **24** retreats from the load-lock module **LLM**, the controller **100** closes the gate valve **GV7**.

(36) The controller **100** controls a suction device (not illustrated) of the load-lock module **LLM** to supply, for example, clean air into the module and switch from the vacuum atmosphere to the ambient air atmosphere in the load-lock module **LLM**.

(37) The controller **100** opens the door valves **GV8** and **GV9**. The controller **100** controls the transfer device **ARM3** to take out the first wafer **W** mounted on the stage **31** of the load-lock module **LLM** and accommodate the first wafer **W** in the carrier **C** of the load port **LP3**. In addition, the controller **100** controls the transfer device **ARM2** to take out the third wafer **W** mounted on the stage **33** of the load-lock module **LLM** and place the third wafer **W** in the delivery section (not illustrated).

(38) Further, the controller **100** controls the transfer device **ARM3** to take out the second wafer **W** mounted on the stage **32** of the load-lock module **LLM** and accommodate the second wafer **W** in the carrier **C** of the load port **LP3**. In addition, the controller **100** controls the transfer device **ARM2** to take out the fourth wafer **W** mounted on the stage **34** of the load-lock module **LLM** and place the fourth wafer **W** in the delivery section (not illustrated). When four wafers **W** are taken out from the stages **31** to **34** of the load-lock module **LLM** and the transfer devices **ARM2** and **ARM3** retreat from the load-lock module **LLM**, the controller **100** closes the door valves **GV8** and **GV9**.

(39) The controller **100** controls the transfer device **ARM3** to take out the third wafer **W** from the delivery section (not illustrated) and accommodate the third wafer **W** in the carrier **C** of the load

port LP3. Additionally, the controller **100** controls the transfer device ARM3 to take out the fourth wafer W from the delivery section (not illustrated) and accommodate the fourth wafer W in the carrier C of the load port LP3.

(40) An example, in which the wafer W is transferred into the process module PM1 and is transferred from the process module PM1, has been described above. However, the wafer W may be similarly transferred into and from the process modules PM2 to PM6. Additionally, the wafer W processed in the process module PM1 may be transferred into the process module PM2, for example, and the wafer W may be further processed in the process module PM2.

(41) <Operation of Mounting the Wafer W in the Process Module PM1>

(42) Next, an example of the operation of mounting the wafers W held by the transfer device ARM1 on the stages **11** to **14** of the process module PM1 will be further described with reference to FIGS. 3A to 3D and FIGS. 4A to 4D. FIGS. 3A to 3D and FIGS. 4A to 4D are perspective views depicting an example of the operation of mounting the wafers W on the stages **11** to **14** of the process module PM1. Here, in FIGS. 3A to 3D and FIGS. 4A to 4D, only the end effector **24**, the stages **11** to **14**, the sensor S1, and the wafers W are illustrated, and other configurations are not illustrated. Additionally, the following description assumes that a direction in which the end effector **24** is inserted into the process module PM1 is the forward direction, and a direction in which the end effector **24** is removed from the process module PM1 is the backward direction.

(43) As illustrated in FIG. 3A, the controller **100** controls the actuator of each joint of the transfer device ARM1 to move the end effector **24** so that the stages **31** to **34** are positioned in the extending direction of the blades **241** and **242**.

(44) Here, the sensor S1 includes sensor units **51** and **52**. The number of sensor units is equal to the number of blades of the end effector **24**. The sensor unit **51** is disposed on a path in which the blade **241** enters the process module PM1. Additionally, the sensor unit **52** is disposed on a path in which the blade **242** enters the process module PM1.

(45) The sensor unit **51** includes two sensor elements **51a** and **51b** that are disposed spaced apart. The sensor elements **51a** and **51b** are, for example, optical passing sensors each including a light emitting unit and a light receiving unit. The sensor elements **51a** and **51b** detect whether there is an object to be detected by irradiating light from the light emitting unit and detecting reflected light from the object to be detected at the light receiving unit. The space between the sensor element **51a** and the sensor element **51b** is wider than the width of the blade **241** and narrower than the diameter of the wafer W. Similarly, the sensor unit **52** also includes two sensor elements **52a** and **52b**.

(46) As illustrated in FIG. 3B, the controller **100** controls the actuator of each joint of the transfer device ARM1 to move forward the end effector **24**. At this time, the blade **241** passes between the sensor element **51a** and the sensor element **51b** in top view. When the holder **244** of the blade **241** positions over the sensor unit **51**, the sensor elements **51a** and **51b** of the sensor unit **51** detect the wafer W, so that the controller **100** can determine whether there is the wafer W in the holder **244** based on the value detected by the sensor unit **51**. Similarly, when the holder **246** positions over the sensor unit **52**, the sensor elements **52a** and **52b** of the sensor unit **52** detect the wafer W, so that the controller **100** can determine whether there is a wafer W in the holder **246** based on the value detected by the sensor unit **52**.

(47) Additionally, the controller **100** acquires a position at which the end effector **24** is situated when the sensor element **51a** starts detecting the wafer W, a position at which the end effector **24** is situated when the sensor element **51a** stops detecting the wafer W, a position at which the end effector **24** is situated when the sensor element **51b** starts detecting the wafer W, and a position at which the end effector **24** is situated when the sensor element **51b** stops detecting the wafer W. The controller **100** can detect a position of the wafer W held in the holder **244** based on position information about these four positions. The controller **100** can detect the shift between the reference point of the holder **244** and the center of the wafer W held in the holder **244** (the eccentricity amount) based on the value detected by the sensor unit **51**. Similarly, the controller **100**

can detect the shift between the reference point of the holder **246** and the center of the wafer **W** held in the holder **246** (the amount of eccentricity) based on the value detected by the sensor unit **52**.

(48) As illustrated in FIG. 3C, the controller **100** controls the actuator of each joint of the transfer device **ARM1** to further move forward the end effector **24**. At this time, when the holder **243** of the blade **241** positions over the sensor unit **51**, the sensor elements **51a** and **51b** of the sensor unit **51** detect the wafer **W**, so that the controller **100** can determine whether there is the wafer **W** in the holder **243** based on the value detected by the sensor unit **51**. Similarly, when the holder **245** positions over the sensor unit **52**, the sensor elements **52a** and **52b** of the sensor unit **52** detect the wafer **W**, so that the controller **100** can determine whether there is the wafer **W** in the holder **245** based on the value detected by the sensor unit **52**.

(49) Additionally, the controller **100** can detect the shift between the reference point of the holder **243** and the center of the wafer **W** held in the holder **243** (the eccentricity amount) based on the value detected by the sensor unit **51**. Similarly, the controller **100** can detect the shift between the reference point of the holder **245** and the center of the wafer **W** held in the holder **245** (the eccentricity amount) based on the value detected by the sensor unit **52**.

(50) As illustrated in FIG. 3D, the controller **100** controls the actuator of each joint of the transfer device **ARM1** to further move forward the end effector **24**. Additionally, based on the position shift of the wafer **W** that is detected by the sensor **S1**, the movement trajectory to be observed until the operation completion of the transfer device **ARM1** is corrected, and the wafer **W** is transferred. Thus, the wafers **W** held in the holders **243** to **246** are positioned over the stages **11** to **14**.

(51) Here, the stages **11** to **14** include lift pins **11a** to **14a**. The lift pins **11a** and **12a** are disposed at positions different from a position through which the blade **241** passes in top view. Additionally, the lift pins **13a** and **14a** are disposed at positions different from a position through which the blade **242** passes. Thus, as illustrated in FIG. 4A, when the lift pins **11a** to **14a** are raised, the lift pins **11a** to **14a** do not contact the blades **241** and **242** and lift four wafers **W** held in the end effector **24**. Here, four wafers **W** are held at the same height in the end effector **24** because the heights of the blades **241** and **242** are equal. Thus, the lift pins **11a** to **14a** may be configured to be raised simultaneously by one lifter.

(52) Next, the controller **100** controls the actuator of each joint of the transfer device **ARM1** to move backward the end effector **24**. Here, as illustrated in FIG. 4B, when the end effector **24** is at the same position as in FIG. 3C, it is checked that the sensor **S1** does not detect the wafer **W**. That is, the controller **100** checks that there are no wafers **W** in the holders **243** and **245** based on the values detected by the sensor **S1**. Here, in FIG. 4B and FIG. 4C, the positions where the wafers **W** were placed are illustrated by dotted lines.

(53) The controller **100** then controls the actuator of each joint of the transfer device **ARM1** to further move backward the end effector **24**. Here, as illustrated in FIG. 4C, when the end effector **24** is at the same position as in FIG. 3B, it is checked that the sensor **S1** does not detect the wafer **W**. That is, the controller **100** checks that there are no wafers **W** in the holders **244** and **246** based on the values detected by the sensor **S1**.

(54) As illustrated in FIG. 4D, by moving backward the end effector **24**, the end effector **24** retreats from the process module **PM1**. Subsequently, the wafers **W** are mounted on the stages **11** to **14** by lowering the lift pins **11a** to **14a**.

(55) An example in which the wafer **W** is transferred into the process module **PM1** has been described above. However, when the wafer **W** is transferred from the process module **PM1**, it is only required that the steps illustrated in FIGS. 3A to 4D are reversed, and the description thereof is omitted. Additionally, the same will apply when the wafer **W** is transferred into the process modules **PM2** to **PM6** or the load-lock module **LLM**, and the overlapping description is omitted.

(56) <Teaching Method>

(57) Next, a method of teaching the transfer devices **ARM1** to **ARM3** will be described. FIG. 5 is

an example of a flowchart depicting a method of teaching the transfer devices ARM1 to ARM3 in a substrate processing system according to a first embodiment. In the present specification, “teaching the transfer device” indicates determining a position of the end effector and instructing the determined position to the transfer device.

(58) In step **S101**, the controller **100** teaches the transfer devices ARM1 to ARM3 with respect to the load-lock module LLM. That is, the controller **100** determines positions of the end effectors of the transfer devices ARM1 to ARM3 with respect to the load-lock module LLM and instructs the determined positions to the transfer devices ARM1 to ARM3.

(59) Here, the controller **100** teaches the position of the end effector **44** of the transfer device ARM3 when the transfer device ARM3 delivers the wafer W to the stage **31** of the load-lock module LLM or when the transfer device ARM3 receives the wafer W from the stage **31** of the load-lock module LLM. For example, a wafer-shaped inspection device with a camera (not illustrated) is mounted on the end effector **44** and transferred over the stage **31**, and the controller **100** teaches a position such that the center of the wafer-shaped inspection device matches with the center of the stage **31**.

(60) Similarly, the controller **100** teaches the position of the end effector **44** of the transfer device ARM3 when the transfer device ARM3 delivers the wafer W to the stage **32** of the load-lock module LLM or when the transfer device ARM3 receives the wafer W from the stage **32** of the load-lock module LLM. Additionally, the controller **100** teaches the position of the end effector **44** of the transfer device ARM2 when the transfer device ARM2 delivers the wafer W to the stage **33** of the load-lock module LLM or when the transfer device ARM2 receives the wafer W from the stage **33** of the load-lock module LLM. Additionally, the controller **100** teaches the position of the end effector **44** of the transfer device ARM2 when the transfer device ARM2 delivers the wafer W to the stage **34** of the load-lock module LLM or when the transfer device ARM2 receives the wafer W from the stage **34** of the load-lock module LLM.

(61) Additionally, the controller **100** teaches the position of the end effector **24** of the transfer device ARM1 when the transfer device ARM1 receives the wafer W from the stages **31** to **34** of the load-lock module LLM or when the transfer device ARM1 delivers the wafer W to the stages **31** to **34** of the load-lock module LLM. For example, wafer-shaped inspection devices with cameras (not illustrated) are mounted on the holders **243** to **246** of the end effector **24** and transferred over the stages **31** to **34**, and the controller **100** teaches a position such that the centers of the wafer-shaped inspection devices match with or are close to the centers of the stages **31** to **34**.

(62) In step **S102**, the controller **100** teaches the transfer device ARM1 with respect to the process module PM1. That is, the controller **100** determines a position of the end effector **24** of the transfer device ARM1 with respect to the process module PM1 and instructs the determined position to the transfer device ARM1.

(63) Here, the controller **100** teaches the position of the end effector **24** of the transfer device ARM1 when the transfer device ARM1 delivers the wafers W to the stages **11** to **14** of the process module PM1 or when the transfer device ARM1 receives the wafers W from the stages **11** to **14** of the process module PM1. For example, wafer-shaped inspection devices with cameras (not illustrated) are mounted on the holders **243** to **246** of the end effectors **24** and transferred over the stages **11** to **14**, and the controller **100** teaches a position such that the centers of the wafer-shaped inspection devices match with or are close to the centers of the stages **11** to **14**.

(64) In step **S103**, the controller **100** measures the shift amounts of the wafers W in the process module PM1 when the wafers W are transferred from the load-lock module LLM to the process module PM1.

(65) Here, the positions of the stages **11** to **14** have individual errors with respect to the design values. Thus, when the wafers W are mounted on the stages **11** to **14**, a shift is generated between the center of each of the stages **11** to **14** and the center of the wafer W mounted thereon.

(66) The controller **100** controls the transfer device ARM1 to receive four wafers W from the stages

31 to **34** at the teaching position in the load-lock module LLM that is set in step **S101**, and measure the shift amount between the center of each of the stages **11** to **14** and the center of the wafer **W** mounted thereon when four wafers **W** are delivered to the stages **11** to **14** at the teaching position in the process module **PM1** that is set in step **S102**. For example, wafer-shaped inspection devices with cameras (not illustrated) are mounted on the stages **31** to **34** and transferred to the stages **11** to **14** by the transfer device **ARM1**, and the shift amount between the center of each of the stages **11** to **14** and the center of the wafer-shaped inspection device mounted thereon is measured.

(67) Here, the method of measuring the shift amounts is not limited thereto. For example, the wafers **W** are mounted on the stages **11** to **14** such that the centers of the stages **11** to **14** respectively match with the centers of the wafers **W**. The wafers **W** are then delivered from the stages **11** to **14** to the holders **243** to **246** of the end effector **24**, and four wafers **W** are delivered over the sensor **S1**. With this method, by detecting the position of the edge of each of the wafers **W** and calculating the center position of each of the wafers **W**, the shift amounts of the respective stages **11** to **14** may be measured.

(68) In step **S104**, the controller **100** corrects the positions (the teaching positions) at which the transfer device **ARM2** or the transfer device **ARM3** delivers the wafers **W** to the stages **31** to **34** of the load-lock module LLM based on the shift amounts measured in step **S103**.

(69) That is, the position (the teaching position) at which the transfer device **ARM3** delivers the wafer **W** to the stage **31** of the load-lock module LLM is corrected based on the shift amount in the stage **11**. Here, the position (the teaching position) at which the wafer **W** is delivered to the stage **31** is corrected such that the shift amount is reduced or is canceled.

(70) Similarly, the position (the teaching position) at which the transfer device **ARM3** delivers the wafer **W** to the stage **32** of the load-lock module LLM is corrected based on the shift amount in the stage **12**. Additionally, the position (the teaching position) at which the transfer device **ARM2** delivers the wafer **W** to the stage **33** of the load-lock module LLM is corrected based on the shift amount in the stage **13**. Additionally, the position (the teaching position) at which the transfer device **ARM2** delivers the wafer **W** to the stage **34** of the load-lock module LLM is corrected based on the shift amount in the stage **14**.

(71) Then, when the transfer device **ARM2** or **ARM3** transfers the wafers **W** from the carrier **C** to the process module **PM1**, the wafers **W** are mounted on the stages **31** to **34** in consideration of the error from the design values in the stages **11** to **14** of the process module **PM1**, and four wafers **W** mounted on the stages **31** to **34** are transferred to the stages **11** to **14**. This can reduce the error between the center of each of the stages **11** to **14** and the center of the wafer **W** mounted thereon.

(72) Additionally, the controller **100** stores respective correction values corresponding to the process modules **PM1** to **PM6**. The controller **100** controls the transfer devices **ARM2** or **ARM3** to mount the wafers **W** to the stages **31** to **34** at positions corrected with correction values corresponding to the process modules **PM1** to **PM6** to which the wafers **W** are to be transferred. This allows the wafers **W** to be mounted in accordance with the shift amounts of the stages **11** to **14** in the process modules **PM1** to **PM6**.

(73) Next, another teaching method of the transfer devices **ARM1** to **ARM3** will be described. FIG. **6** is an example of a flowchart illustrating a method of teaching the transfer devices **ARM1** to **ARM3** in a substrate processing system according to a second embodiment.

(74) In step **S201**, the controller **100** teaches the transfer devices **ARM1** to **ARM3** with respect to the load-lock module LLM.

(75) In step **S202**, the controller **100** teaches the transfer device **ARM1** with respect to the process module **PM1**.

(76) In step **S203**, the controller **100** measures the shift amounts of the wafers **W** in the process module **PM1** when the wafer **W** is transferred from the load-lock module LLM to the process module **PM1**.

(77) Here, the processing in steps **S201** to **S203** is substantially the same as the processing in steps

S101 to **S103**, and the overlapping description is omitted.

(78) In step **S204**, the controller **100** calculates a common shift component and individual shift components with respect to the four wafers **W** mounted in the stages **11** to **14**, based on the shift amounts measured in step **S103**.

(79) Here, the shift amount of each of the stages **11** to **14** will be described with reference to FIG. 7. FIG. 7 is an example of a plan view depicting the shift amount in each of the stages **11** to **14** of the process module **PM1**.

(80) An actual shift amount **101** in the stage **11** measured in step **S203** is represented by a solid arrow. Similarly, an actual shift amount **102** in the stage **12** is represented by a solid arrow.

Additionally, an actual shift amount **103** in the stage **13** is represented by a solid arrow.

Additionally, an actual shift amount **104** of the stage **14** is represented by a solid arrow.

(81) Here, the controller **100** calculates a shift component **200** that is common among the shift amounts **101** to **104** and individual shift components **301** to **304** based on the shift amounts **101** to **104** measured in step **S203**. Here, the sum of the common shift component **200** and the individual shift component **301** is the shift amount **101**. The sum of the common shift component **200** and the individual shift component **302** is the shift amount **102**. The sum of the common shift component **200** and the individual shift component **303** is the shift amount **103**. The sum of the common shift component **200** and the individual shift component **304** is the shift amount **104**. The common shift component **200** is represented by a dash-dot-dash arrow. The individual shift components **301** to **304** are represented by dashed arrow.

(82) For example, the controller **100** calculates the common shift component **200** such that the maximum of the individual shift components **301** to **304** is reduced. That is, the common shift component **200** is calculated such that the correction amount in step **S206**, which will be described later, is reduced.

(83) Here, the method of calculating the common shift component **200** and the individual shift components **301** to **304** is not limited thereto.

(84) Returning to FIG. 6, in step **S205**, the controller **100** corrects the position (the teaching position) at which the transfer device **ARM1** delivers the wafers **W** to the stages **11** to **14** of the process module **1** based on the common shift component **200** calculated in step **S204**.

(85) That is, the position (the teaching position) at which the transfer device **ARM1** delivers the wafers **W** to the stages **11** to **14** of the process module **PM1** is corrected based on the common shift component **200**. Here, the delivery position (the teaching position) is corrected to cancel the common shift component **200**.

(86) In step **S206**, the controller **100** corrects the positions (the teaching positions) at which the transfer device **ARM2** or the transfer device **ARM3** delivers the wafers **W** to the stages **31** to **34** of the load-lock module **LLM** based on the individual shift components **301** to **304** calculated in step **S204**.

(87) That is, the position (the teaching position) at which the transfer device **ARM3** delivers the wafer **W** to the stage **31** of the load-lock module **LLM** is corrected based on the individual shift component **301** in the stage **11**. Here, the position (the teaching position) at which the wafer **W** is delivered to the stage **31** is corrected to cancel the individual shift component **301**.

(88) Similarly, the position (the teaching position) at which the transfer device **ARM3** delivers the wafer **W** to the stage **32** of the load-lock module **LLM** is corrected based on the individual shift component **302** in the stage **12**. Additionally, the position (the teaching position) at which the transfer device **ARM2** delivers the wafer **W** to the stage **33** of the load-lock module **LLM** is corrected based on the individual shift component **303** in the stage **13**. Additionally, the position (the teaching position) at which the transfer device **ARM2** delivers the wafer **W** to the stage **34** of the load-lock module **LLM** is corrected based on the individual shift component **304** in the stage **14**.

(89) FIG. 8 is an example of a plan view depicting the correction amount in each of the stages **31** to

34 of the load-lock module LLM. A correction amount **401** in the stage **31** is set to cancel the individual shift component **301** illustrated in FIG. 7. For example, the correction amount **401** is directed opposite to the individual shift component **301** and the absolute value of the correction amount **401** is equal to the absolute value of the individual shift component **301**.

(90) Similarly, a correction amount **402** in the stage **32** is set to cancel the individual shift component **302** illustrated in FIG. 7. A correction amount **403** in the stage **33** is set to cancel the individual shift component **303** illustrated in FIG. 7. A correction amount **404** in the stage **34** is set to cancel the individual shift component **304** illustrated in FIG. 7.

(91) This allows the wafers W to be mounted on the stages **31** and **34** in consideration of the individual shift components **301** and **304** in the stages **11** and **14** of the process module PM1, when the transfer device ARM2 or ARM3 transfers the wafers W from the carrier C to the process module PM1. When the transfer device ARM1 transfers four wafers W mounted on the stages **31** to **34** to the stages **11** to **14**, the wafers W are mounted on the stages **11** to **14** in consideration of the common shift component **200**. This can reduce the error between the center of each of the stages **11** to **14** and the center of the wafer W mounted thereon.

(92) Additionally, the controller **100** stores the respective correction values corresponding to the process modules PM1 to PM6. The controller **100** controls the transfer devices ARM2 or ARM3 to mount the wafers W on the stages **31** to **34** at the positions corrected with the correction values corresponding to the process modules PM1 to PM6 to which the wafers W are to be transferred. This allows the wafers W to be mounted in accordance with the shift amounts of the stages **11** to **14** in the process modules PM1 to PM6.

(93) Further, according to the method of teaching the transfer devices ARM1 to ARM3 in the substrate processing system according to the second embodiment, the shift amount can be divided into the common shift amount used by the transfer device ARM1 and the individual shift amounts used by the transfer devices ARM2 and ARM3. This can expand the correction allowable range by dividing a shift amount that is greater than the correction allowable range of the transfer devices ARM1 to ARM3 into the common shift amount used by the transfer device ARM1 and the individual shift amounts used by the transfer devices ARM2 and ARM3. Additionally, because the correction amount of each of the transfer devices ARM1 to ARM3 can be reduced, a high correction accuracy is maintained thereby.

(94) According to one aspect of the present disclosure, a substrate processing system that transfers a substrate in consideration of a shift of a stage and a method of teaching a transfer device can be provided.

(95) Although the substrate processing system has been described above, the present disclosure is not limited to the above-described embodiments and the like, and various modifications and improvements can be made within the scope of the subject matter of the present disclosure as claimed.

Claims

1. A substrate processing system comprising: a load-lock module including a plurality of load-lock module stages; a process module including a plurality of process module stages; a vacuum transfer module that connects the load-lock module to the process module; a first transfer device including a first arm and configured to transfer a plurality of substrates from the plurality of load-lock module stages to the plurality of process module stages, the first transfer device being provided in the vacuum transfer module; a second transfer device including a second arm and configured to transfer the plurality of substrates to the plurality of load-lock module stages; and a processor configured to perform: teaching a position at which the first transfer device receives the plurality of substrates from the load-lock module; teaching a position at which the first transfer device delivers the plurality of substrates to the process module; measuring shift amounts between the plurality of

process module stages and the plurality of substrates mounted on the plurality of process module stages, the shift amounts being measured after the transferring of the first transfer device; and correcting positions at which the second transfer device delivers the plurality of substrates to the plurality of load-lock module stages based on the measured shift amounts.

2. A substrate processing system comprising: a load-lock module including a plurality of load-lock module stages; a process module including a plurality of process module stages; a vacuum transfer module that connects the load-lock module to the process module; a first transfer device including a first arm and configured to transfer a plurality of substrates from the plurality of load-lock module stages to the plurality of process module stages, the first transfer device being provided in the vacuum transfer module; a second transfer device including a second arm and configured to transfer the plurality of substrates to the plurality of load-lock module stages; and a processor configured to perform: teaching a position at which the first transfer device receives the plurality of substrates from the load-lock module; teaching a position at which the first transfer device delivers the plurality of substrates to the process module; measuring a first shift amount and a second shift amount between the plurality of process module stages and the plurality of substrates mounted on the plurality of process module stages; correcting the position at which the first transfer device delivers the plurality of substrates to the process module based on a first shift component; and correcting positions at which the second transfer device delivers the plurality of substrates to the plurality of load-lock module stages based on a second shift component and a third shift component, wherein the measured first shift amount is a sum of the first shift component and the second shift component and the measured second shift amount is a sum of the first shift component and the third shift component.

3. A method of teaching a transfer device in a substrate processing system including a load-lock module including a plurality of load-lock module stages, a process module including a plurality of process module stages, a vacuum transfer module that connects the load-lock module to the process module, a first transfer device including a first arm and configured to transfer a plurality of substrates from the plurality of load-lock module stages to the plurality of process module stages, the first transfer device being provided in the vacuum transfer module, a second transfer device including a second arm and configured to transfer the plurality of substrates to the plurality of load-lock module stages, and a processor, the method comprising: teaching a position at which the first transfer device receives the plurality of substrates from the load-lock module; teaching a position at which the first transfer device delivers the plurality of substrates to the process module; measuring shift amounts between the plurality of process module stages and the plurality of substrates mounted on the plurality of process module stages, the shift amounts being measured after the transferring of the first transfer device; and correcting load-lock module positions at which the second transfer device delivers the plurality of substrates to the plurality of load-lock module stages based on the measured shift amounts.

4. The method as claimed in claim 3, wherein the correcting of the load-lock module positions includes correcting a position in each of the plurality of load-lock module stages based on an amount of the shift amounts in a corresponding stage among the plurality of process module stages.

5. The method as claimed in claim 3, further comprising correcting a process module position at which the first transfer device delivers the plurality of substrates to the process module, wherein the measured shift amounts include a first shift amount and a second shift amount, wherein the correcting of the process module position includes correcting based on a first shift component, wherein the correcting of the load-lock module positions includes correcting positions in the plurality of load-lock module stages based on a second shift component and a third shift component, and wherein the first shift amount is a sum of the first shift component and the second shift component and the second shift amount is a sum of the first shift component and the third shift component.
